## NSN 5961-01-644-5793

A110a0

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End Application:
F-15sa
Special Features:
Difused junction; high current capability and low forward voltage drop; surge overload rating to 30a peak; low reverse leakage current; rms
reversevol 280; avg rectified output current 1.0; forward vol 1.0; maximum dc blocking vol temp +150
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig: